This device is designed for low level analog switching, sample and hold circuits and chopper stabalized amplifiers. Sourced from Process 51. See J111 for characteristics.
Absolute Maximum Ratings*
$\mathrm{TA}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter |  | Value | Units |
| :---: | :---: | :---: | :---: | :---: |
| $V_{\text {DG }}$ | Drain-Gate Voltage |  | 30 | V |
| $\mathrm{V}_{\text {GS }}$ | Gate-Source Voltage |  | -30 | V |
| $\mathrm{I}_{\mathrm{GF}}$ | Forward Gate Current |  | 50 | mA |
| $\mathrm{T}_{\mathrm{j}}, \mathrm{T}_{\text {stg }}$ | Operating and Storage Junction Temperature Range |  | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| *These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. <br> NOTES: <br> 1) These ratings are based on a maximum junction temperature of 150 degrees $C$. <br> 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations |  |  |  |  |
| Symbol | Characteristic | Max |  | Units |
|  |  | PN4391-4393 | *MMBF4391-4393 |  |
| $\mathrm{P}_{\mathrm{D}}$ | Total Device Dissipation Derate above $25^{\circ} \mathrm{C}$ | $\begin{aligned} & \hline 625 \\ & 5.0 \\ & \hline \end{aligned}$ | $\begin{gathered} 350 \\ 2.8 \\ \hline \end{gathered}$ | $\begin{gathered} \mathrm{mW} \\ \mathrm{~mW} /{ }^{\circ} \mathrm{C} \end{gathered}$ |
| $\mathrm{R}_{\text {өJC }}$ | Thermal Resistance, Junction to Case | 125 |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {өJA }}$ | Thermal Resistance, Junction to Ambient | 357 | 556 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

[^0]Electrical Characteristics $\mathrm{TA}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Max | Units |
| :--- | :---: | :---: | :---: | :---: | :---: |

OFF CHARACTERISTICS

| $\mathrm{V}_{\text {(BR)GSS }}$ | Gate-Source Breakdown Voltage | $\mathrm{I}_{\mathrm{G}}=1.0 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{DS}}=0$ | -30 |  | V |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {gss }}$ | Gate Reverse Current |  |  | $\begin{array}{r} -1.0 \\ -0.2 \end{array}$ | $\begin{aligned} & \hline \mathrm{nA} \\ & \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{GS}}(\mathrm{off}$ ) | Gate-Source Cutoff Voltage | $\begin{array}{ll}V_{D S}=20 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=1.0 \mathrm{nA} & 4391 \\ & 4392 \\ & \mathbf{4 3 9 3}\end{array}$ | $\begin{aligned} & -4.0 \\ & -2.0 \\ & -0.5 \end{aligned}$ | $\begin{array}{r} \hline-10 \\ -5.0 \\ -3.0 \\ \hline \end{array}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{GS}(\mathrm{f})}$ | Gate-Source Forward Voltage | $\mathrm{I}_{\mathrm{G}}=1.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{DS}}=0$ |  | 1.0 | V |
| $\mathrm{I}_{\text {(off) }}$ | Drain Cutoff Leakage Current |   <br> $V_{D S}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=-12 \mathrm{~V}$ $\mathbf{4 3 9 1}$ <br> $\mathrm{~V}_{\mathrm{DS}}=20 \mathrm{~V}, \mathrm{~V}$ GS $=-7.0 \mathrm{~V}$ $\mathbf{4 3 9 2}$ <br> $\mathrm{~V}_{\mathrm{DS}}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=-5.0 \mathrm{~V}$ $\mathbf{4 3 9 3}$ <br> $\mathrm{~V}_{\mathrm{DS}}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=-12 \mathrm{~V}$,  <br> $\mathrm{T}_{\mathrm{A}}=150^{\circ} \mathrm{C}$  <br> $\mathrm{V}_{\mathrm{DS}}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=-7.0 \mathrm{~V}$,  <br> $\mathrm{T}_{\mathrm{A}}=150^{\circ} \mathrm{C}$  <br> $\mathrm{V}_{\mathrm{DS}}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=-5.0 \mathrm{~V}$,  <br> $\mathrm{T}_{\mathrm{A}}=150^{\circ} \mathrm{C}$ $\mathbf{4 3 9 3}$ |  | $\begin{aligned} & \hline 0.1 \\ & 0.1 \\ & 0.1 \\ & 0.2 \\ & 0.2 \\ & 0.2 \end{aligned}$ | nA <br> nA <br> nA <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |

ON CHARACTERISTICS

| IDSs | Zero-Gate Voltage Drain Current* | $\mathrm{V}_{\mathrm{DS}}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0$ | $\begin{aligned} & \hline 4391 \\ & 4392 \\ & 4393 \end{aligned}$ | $\begin{aligned} & 50 \\ & 25 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & \hline 150 \\ & 75 \\ & 30 \end{aligned}$ | $\begin{aligned} & \hline \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {DS(on) }}$ | Drain-Source On Voltage | $\begin{aligned} & \mathrm{I}_{\mathrm{D}}=12 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=0 \\ & \mathrm{I}_{\mathrm{D}}=6.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=0 \\ & \mathrm{I}_{\mathrm{D}}=3.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=0 \end{aligned}$ | $\begin{aligned} & \hline 4391 \\ & 4392 \\ & 4393 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & 0.4 \\ & 0.4 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \hline \mathrm{V} \\ & \mathrm{~V} \\ & \mathrm{~V} \end{aligned}$ |
| $r_{\text {PS(on) }}$ | Drain-Source On Resistance | $\mathrm{I}_{\mathrm{D}}=1.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=0$ | $\begin{aligned} & \hline 4391 \\ & 4392 \\ & 4393 \\ & \hline \end{aligned}$ |  | $\begin{gathered} 30 \\ 60 \\ 100 \end{gathered}$ | $\Omega$ $\Omega$ $\Omega$ |

SMALL-SIGNAL CHARACTERISTICS

| rds(on) | Drain-Source On Resistance | $V_{D S}=$ $V_{G S}=0, f=1.0 \mathrm{kHz}$ <br>  4391 <br>  4392 <br>  4393 | $\begin{gathered} \hline 30 \\ 60 \\ 100 \end{gathered}$ | $\begin{gathered} \hline \Omega \\ \Omega \\ \Omega \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: |
| Ciss | Input Capacitance | $\mathrm{V}_{\mathrm{DS}}=20, \mathrm{~V}_{\mathrm{GS}}=0, \mathrm{f}=1.0 \mathrm{MHz}$ | 14 | pF |
| $\mathrm{Crss}^{\text {r }}$ | Reverse Transfer Capacitance | $\mathrm{V}_{\mathrm{GS}}=-12 \mathrm{~V}, \mathrm{f}=1.0 \mathrm{MHz}$ 4391 <br> $\mathrm{~V}_{\mathrm{GS}}=-7.0 \mathrm{~V}, \mathrm{f}=1.0 \mathrm{MHz}$ 4392 <br> $\mathrm{~V}_{\mathrm{GS}}=-5.0 \mathrm{~V}, \mathrm{f}=1.0 \mathrm{MHz}$ 4393 | $\begin{aligned} & \hline 3.5 \\ & 3.5 \\ & 3.5 \end{aligned}$ | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |

## SWITCHING CHARACTERISTICS

| $\mathrm{tr}_{r}$ | Rise Time | $\begin{aligned} & \mathrm{I}_{\mathrm{D}(\text { (n) }}=12 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{D}(\text { (n) }}=6.0 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{D}(\text { (on) }}=3.0 \mathrm{~mA} \\ & \hline \end{aligned}$ | $\begin{aligned} & 4391 \\ & 4392 \\ & 4393 \\ & \hline \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 5.0 \\ & 5.0 \end{aligned}$ | ns ns ns |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{f}$ | Fall Time | $\begin{aligned} & \mathrm{V}_{\mathrm{GS}(\text { (ff) }}=12 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{GS}(\text { off })}=6.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{GS}(\text { off })}=3.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4391 \\ & 4392 \\ & 4393 \\ & \hline \end{aligned}$ | 15 20 30 | ns ns ns |
| ton | Turn-On Time | $\begin{aligned} & I_{\mathrm{D}(\text { (on })}=12 \mathrm{~mA} \\ & I_{\mathrm{D}(\text { (on })}=6.0 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{D}(\text { (n) })}=3.0 \mathrm{~mA} \\ & \mathrm{I}^{2} \end{aligned}$ | $\begin{aligned} & 4391 \\ & 4392 \\ & 4393 \\ & \hline \end{aligned}$ | 15 15 15 | ns ns ns |
| $\mathrm{t}_{\text {off }}$ | Turn-Off Time | $\begin{aligned} & \mathrm{V}_{\mathrm{GS}(\text { (ff })}=12 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{GS}(\text { off })}=6.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{GS}(\text { off })}=3.0 \mathrm{~V} \\ & \hline \end{aligned}$ | $\begin{aligned} & 4391 \\ & 4392 \\ & 4393 \\ & \hline \end{aligned}$ | 20 35 50 | ns ns ns |

${ }^{*}$ Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 1.0 \%$

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## TO-92 Tape and Reel Data, continued

## TO-92 Reeling Style

## Configuration: Figure 2.0



Style "A", D26Z, D70Z (s/h)

## TO-92 Radial Ammo Packaging

## Configuration: Figure 3.0




Style "E", D27Z, D71Z (s/h)


## TO-92 Tape and Reel Data, continued

TO-92 Tape and Reel Taping
Dimension Configuration: Figure 4.0


## TO－92 Package Dimensions <br> FAIRCHILD

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## TO－92（FS PKG Code 92，94，96）



Scale 1：1 on letter size paper Dimensions shown below are in： inches［millimeters］
Part Weight per unit（gram）： 0.1977


## SOT-23 Tape and Reel Data

SOT-23 Packaging Configuration: Figure 10


| SOT-23 PackagingInformation |  |  |
| :--- | :---: | :---: |
| Packaging Option | Standard <br> (noflow code) | D87Z |
| Packagingtype | TNR | TNR |
| Qty per Reel/Tube/Bag | 3,000 | 10,000 |
| Reel Size | $7{ }^{\prime \prime}$ Dia | $13^{\prime \prime}$ |
| Box Dimension (mm) | $187 \times 107 \times 183$ | $343 \times 343 \times 64$ |
| Max qty per Box | 24,000 | 30,000 |
| Weight per unit (gm) | 0.0082 | 0.0082 |
| Weight per Reel (kg) | 0.1175 | 0.4006 |
| Note/Comments |  |  |
|  |  |  |

Human Readable Label sample


SOT-23 Tape Leader and Trailer Configuration: Figure 20

Human readable Label


## SOT-23 Tape and Reel Data, continued

## SOT-23 Embossed Carrier Tape

## Configuration: Figure 3.0



| Dimensions are in millimeter |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Pkg type | A0 | во | w | Do | D1 | E1 | E2 | F | P1 | P0 | ко | T | Wc | Tc |
| $\begin{gathered} \text { SOT-23 } \\ (8 \mathrm{~mm}) \\ \hline \end{gathered}$ | ${ }_{\substack{3.15 \\+0.10}}$ | ${ }_{\text {cher }}^{\substack{2.77 \\+0.10}}$ | ${ }_{+0.0}^{8.0}$ | ${ }_{\substack{1.55 \\++0.05}}$ | $\begin{aligned} & 1.125 \\ & +1-0.125 \end{aligned}$ | ${ }_{\substack{1.75 \\+-0.10}}$ | $\substack{6.25 \\ \text { min }}_{\substack{\text { che }}}$ | ${ }_{\substack{3.50 \\+-0.05}}$ | $\underset{\substack{4.0 \\+0.1}}{\text { ¢ }}$ | $\underset{\substack{4.0 \\+-0.1}}{\text { ¢ }}$ | ${ }_{\substack{1.30 \\++0.10}}$ | $\underbrace{}_{\substack{0.228 \\+1-0.13}}$ | $\underset{+}{5.2}$ | ${ }_{\substack{0.06 . \\+-0.02}}^{\substack{\text { a }}}$ |

Notes: AO, BO, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).


SOT-23 Reel Configuration: Figure 4.0


Sketch C (Top View)
Component lateral movement

Sketch B (Top View)
Component Rotation


13" Diameter Option
W2 max Measured at Hub


7"Diameter Option


DETAIL AA

| Dimensions are in inches and millimeters |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Tape Size | Reel Option | Dim A | Dim B | Dim C | Dim D | Dim N | Dim W1 | Dim W2 | Dim W3 (LSL-USL) |
| 8 mm | 7" Dia | $\begin{aligned} & 7.00 \\ & 177.8 \end{aligned}$ | $\begin{aligned} & 0.059 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & 512+0.020 /-0.008 \\ & 13+0.5 /-0.2 \end{aligned}$ | $\begin{aligned} & 0.795 \\ & 20.2 \end{aligned}$ | $\begin{aligned} & 2.165 \\ & 55 \end{aligned}$ | $\begin{aligned} & 0.331+0.059 /-0.000 \\ & 8.4+1.5 / 0 \end{aligned}$ | $\begin{aligned} & 0.567 \\ & 14.4 \end{aligned}$ | $\begin{aligned} & 0.311-0.429 \\ & 7.9-10.9 \end{aligned}$ |
| 8 mm | 13 " Dia | $\begin{aligned} & 13.00 \\ & 330 \end{aligned}$ | $\begin{aligned} & 0.059 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & 512+0.020 /-0.008 \\ & 13+0.5 /-0.2 \end{aligned}$ | $\begin{aligned} & 0.795 \\ & 20.2 \end{aligned}$ | $\begin{aligned} & 4.00 \\ & 100 \end{aligned}$ | $\begin{aligned} & 0.331+0.059 /-0.000 \\ & 8.4+1.5 / 0 \end{aligned}$ | $\begin{aligned} & 0.567 \\ & 14.4 \end{aligned}$ | $\begin{aligned} & 0.311-0.429 \\ & 7.9-10.9 \end{aligned}$ |

## SOT-23 (FS PKG Code 49)



Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters]
Part Weight per unit (gram): 0.0082


LAND PATTERN RECOMMENDATION


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| FACT ${ }^{\text {m }}$ | OPTOPLANAR ${ }^{\text {TM }}$ | SuperSOTTM-3 |  |
| FACT Quiet Series ${ }^{\text {TM }}$ | PACMAN ${ }^{\text {TM }}$ | SuperSOT™-6 |  |
| FAST ${ }^{\text {® }}$ | POP ${ }^{\text {TM }}$ | SuperSOT™-8 |  |

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[^0]:    * Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

